# SL2320B

## 20V/6A N-Channel MOSFET

### Features

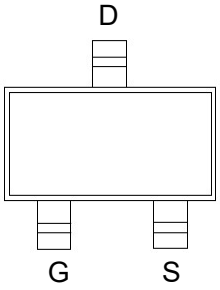
- Trench Power LV MOSFET technology
- High Power and current handing capability

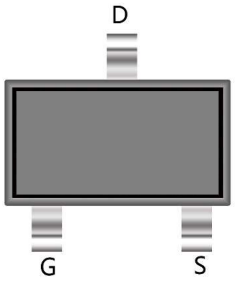
### Product Summary

| $V_{DS}$ | $R_{DS(ON)}$ MAX | $I_D$ MAX |
|---|---|---|
| 20V | 18mΩ@4.5V | 6A |
| | 22mΩ@2.5V | |

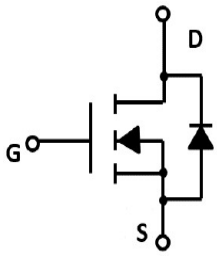
### Application

- PWM application
- Load switch




SOT-23-3L top view



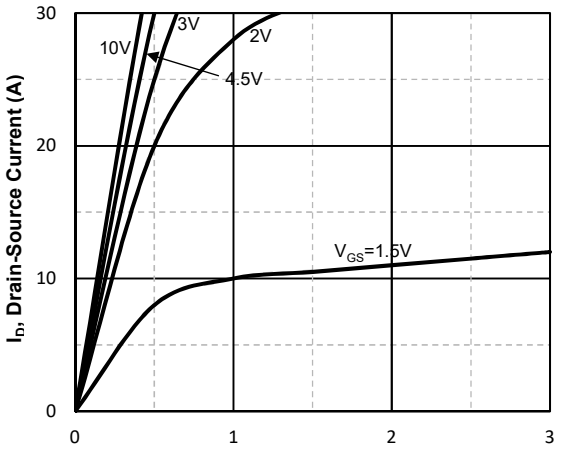

Schematic diagram

Pb-Free RoHS

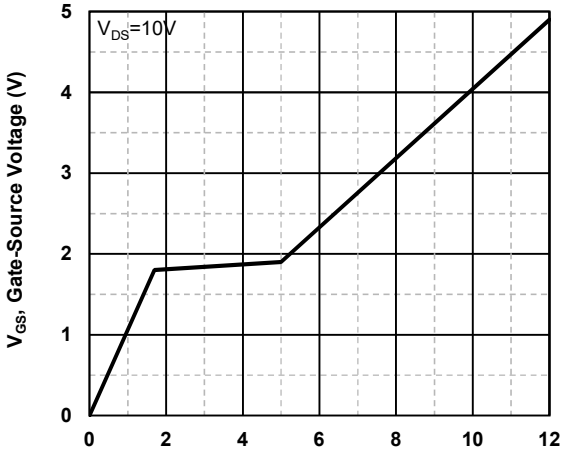
| Absolute Maximum Ratings (TA=25℃unless otherwise noted) | | | | |
|---|---|---|---|---|
| **Symbol** | **Parameter** | | **Rating** | **Unit** |
| **Common Ratings (TC=25°C Unless Otherwise Noted)** | | | | |
| $V_{DS}$ | Drain-Source Breakdown Voltage | | 20 | V |
| $V_{GS}$ | Gate-Source Voltage | | ±10 | V |
| $T_J$ | Maximum Junction Temperature | | 150 | °C |
| $T_{STG}$ | Storage Temperature Range | | -50 to 155 | °C |
| $I_S$ | Diode Continuous Forward Current | Tc=25°C | 6 | A |
| **Mounted on Large Heat Sink** | | | | |
| $I_{DM}$ | Pulse Drain Current Tested | Tc=25°C | 25 | A |
| $I_D$ | Continuous Drain Current | Tc=25°C | 6 | A |
| $P_D$ | Maximum Power Dissipation | Tc=25°C | 1.25 | W |
| $R_{\theta JA}$ | Thermal Resistance Junction-to-Ambient | | 100 | °C/ W |

| Electrical Characteristics (TJ=25℃ unless otherwise noted) | | | | | | |
|---|---|---|---|---|---|---|
| **Symbol** | **Parameter** | **Condition** | **Min** | **Typ** | **Max** | **Unit** |
| **Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)** | | | | | | |
| $BV_{(BR)DSS}$ | Drain-Source Breakdown Voltage | $V_{GS}$=0V, $I_D$=250μA | 20 | -- | -- | V |
| $I_{DSS}$ | Zero Gate Voltage Drain Current | $V_{DS}$=20V, $V_{GS}$=0V | -- | -- | 1 | μA |
| $I_{GSS}$ | Gate-Body Leakage Current | $V_{GS}$=±10V, $V_{DS}$=0V | -- | -- | ±100 | nA |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS}$=$V_{GS}$, $I_D$=250μA | 0.45 | 0.7 | 1.0 | V |
| $R_{DS(on)}$ | Drain-Source On-State Resistance | $V_{GS}$=4.5V, $I_D$=5A | -- | 12 | 18 | mΩ |
| | | $V_{GS}$=2.5V, $I_D$=4A | -- | 15 | 22 | mΩ |
| **Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)** | | | | | | |
| $C_{ISS}$ | Input Capacitance | $V_{DS}$=10V, $V_{GS}$=0V, f=1MHz | -- | 885 | -- | pF |
| $C_{OSS}$ | Output Capacitance | | -- | 135 | -- | pF |
| $C_{RSS}$ | Reverse Transfer Capacitance | | -- | 120 | -- | pF |
| **Switching Characteristics** | | | | | | |
| $Q_g$ | Total Gate Charge | $V_{DS}$=10V, $I_D$=6A, $V_{GS}$=4.5V | -- | 11 | -- | nC |
| $Q_{gs}$ | Gate Source Charge | | -- | 1.75 | -- | nC |
| $Q_{gd}$ | Gate Drain Charge | | -- | 3 | -- | nC |
| $t_{d(on)}$ | Turn-on Delay Time | $V_{DD}$=10V, $R_L$=1.5Ω, $V_{GS}$=4.5V, $R_G$=3Ω | -- | 7 | -- | nS |
| $t_r$ | Turn-on Rise Time | | -- | 45 | -- | nS |
| $t_{d(off)}$ | Turn-Off Delay Time | | -- | 30 | -- | nS |
| $t_f$ | Turn-Off Fall Time | | -- | 50 | -- | nS |
| **Source- Drain Diode Characteristics** | | | | | | |
| $V_{SD}$ | Forward on voltage | Tj=25℃, Is=6A | -- | -- | 1.2 | V |

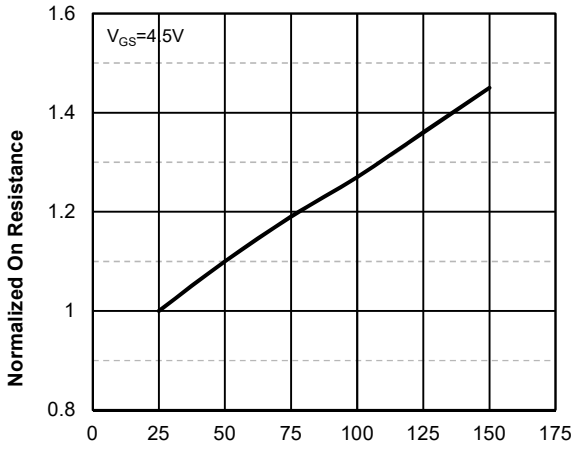
## Typical Operating Characteristics



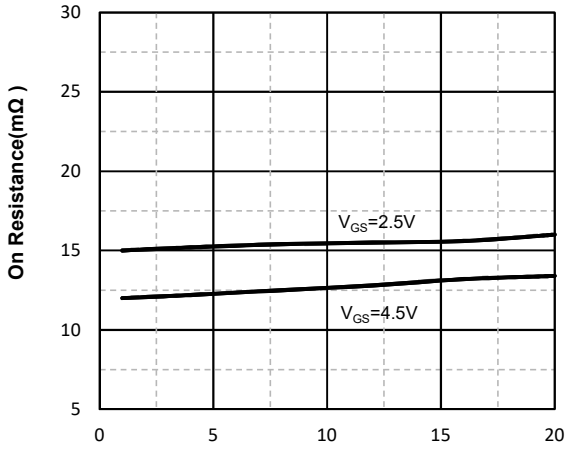

$V_{DS}$, Drain -Source Voltage (V)
Fig1. Typical Output Characteristics



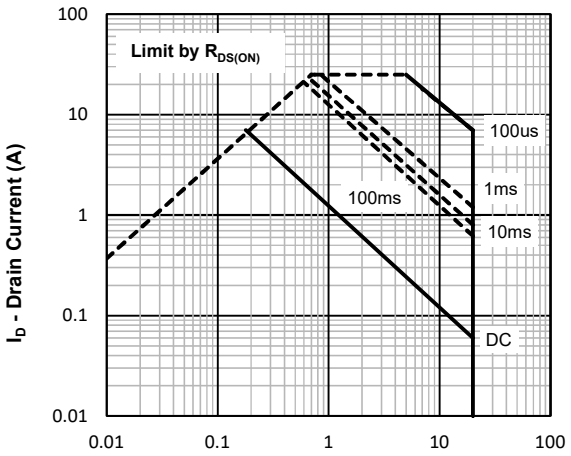

Qg -Total Gate Charge (nC)
Fig2. Typical Gate Charge Vs.Gate-Source Voltage



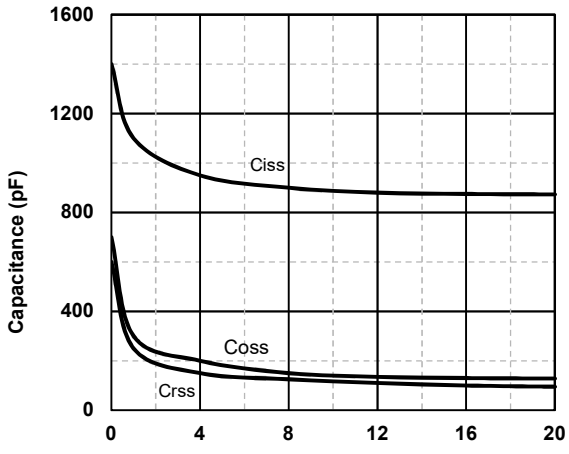

Tj - Junction Temperature (°C)
Fig3. Normalized On-Resistance Vs. Temperature




$I_D$, Drain-Source Current (A)
Fig4. On-Resistance Vs. Drain-Source Current

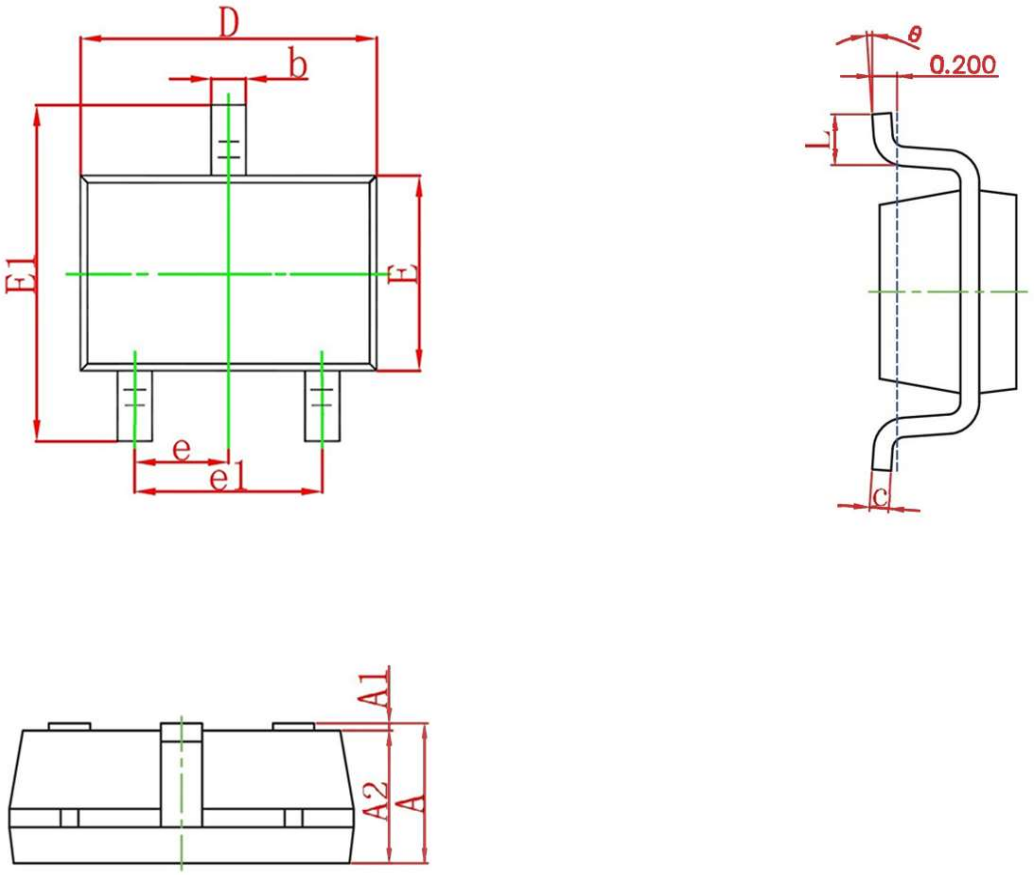



$V_{DS}$, Drain -Source Voltage (V)
Fig5. Maximum Safe Operating Area




$V_{DS}$ , Drain-Source Voltage (V)
Fig6. Typical Capacitance Vs.Drain-Source Voltage

## SOT-23-3L Package information




| Symbol | Dimensions in Millimeters(mm) | | Dimensions In Inches | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| A | 1.050 | 1.250 | 0.042 | 0.050 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.042 | 0.046 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.112 | 0.120 |
| E | 1.500 | 1.700 | 0.060 | 0.068 |
| E1 | 2.650 | 2.950 | 0.106 | 0.118 |
| e | 0.950TYP | | 0.037TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |